

Surface Mount Ultra Fast Power Rectifier

POWERMITE® Power Surface Mount Package

NHPM120, NRVHPM120

This ultrafast POWERMITE provides soft recovery fast switching performance in a compact thermally efficient package. The advanced packaging techniques provide for a very efficient micro-miniature space-saving surface mount rectifier. With its unique heatsink design, the POWERMITE offers thermal performance similar to the SMA while being 50% smaller in footprint area.

Features

- Fast Soft Switching for Reduced EMI and Higher Efficiency
- Low Profile Maximum Height of 1.1 mm
- Small Footprint Footprint Area of 8.45 mm²
- Supplied in 12 mm Tape and Reel
- Low Thermal Resistance with Direct Thermal Path of Die on Exposed Cathode Heat Sink
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Mechanical Characteristics:

- POWERMITE is JEDEC Registered as D0-216AA
- Case: Molded Epoxy
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 16.3 mg (Approximately)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Maximum for 10 Seconds
- MSL 1

Applications

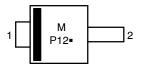
- Automotive LED Lighting
- Engine Control
- Freewheeling Diode Where Space is at a Premium
- Flat Panel Display

ULTRAFAST RECTIFIER 1.0 AMPERE, 200 VOLTS



POWERMITE CASE 457

MARKING DIAGRAM



M = Date CodeP12 = Device Code■ = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping [†]
NRVHPM120T3G	POWERMITE (Pb-Free)	12,000 / Tape & Reel

DISCONTINUED (Note 1)

NHPM120T3G	POWERMITE	12,000 /
	(Pb-Free)	Tape & Reel

- †For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.
- DISCONTINUED: These devices are not recommended for new design. Please contact your onsemi representative for information. The most current information on these devices may be available on www.onsemi.com.

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MAXIMUM RATINGS

Symbol	Rating	Value	Unit
V _{RRM} V _{RWM} V _R	Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	200	V
I _O	Average Rectified Forward Current (T _L = 165°C)	1.0	Α
I _{FRM}	Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz) T_L = 165°C	2.0	Α
I _{FSM}	Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	30	Α
T _{stg} , T _J	Storage and Operating Junction Temperature Range (Note 2)	-65 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Symbol	Characteristic	Value	Unit
$\Psi_{\sf JCL}$	Thermal Resistance, Junction-to-Lead (Note 3)	12	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction-to-Ambient (Note 3)	75	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (Note 4)	260	°C/W

ELECTRICAL CHARACTERISTICS

Symbol	Characteristic	Value	Unit
V _F	Maximum Instantaneous Forward Voltage (Note 5) $ \begin{array}{l} (I_F=1.0 \text{ A, } T_J=25^{\circ}\text{C}) \\ (I_F=2.0 \text{ A, } T_J=25^{\circ}\text{C}) \\ (I_F=1.0 \text{ A, } T_J=125^{\circ}\text{C}) \\ (I_F=2.0 \text{ A, } T_J=125^{\circ}\text{C}) \end{array} $	1.0 1.1 0.85 0.95	V
I _R	Maximum Instantaneous Reverse Current (Note 5) (Rated dc Voltage, $T_J = 25$ °C) (Rated dc Voltage, $T_J = 125$ °C)	0.5 25	μΑ
t _{rr}	Reverse Recovery Time $I_F = 1.0 \text{ A}, V_R = 30 \text{ V}, \text{ dl/dt} = 50 \text{ A/}\mu\text{s}, T_J = 25^{\circ}\text{C}$	25	ns
t _{rr}	Reverse Recovery Time $I_F = 1.0 \text{ A}, V_R = 30 \text{ V}, \text{ dl/dt} = 50 \text{ A/}\mu\text{s}, T_J = 50^{\circ}\text{C}$	50	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- Mounted with 700 mm² copper pad size (Approximately 1 in²) 1 oz FR4 Board.
 Mounted with pad size approximately 20 mm² copper, 1 oz FR4 Board.
 Pulse Test: Pulse Width ≤ 380 μs, Duty Cycle ≤ 2.0%.

^{2.} The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

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TYPICAL CHARACTERISTICS

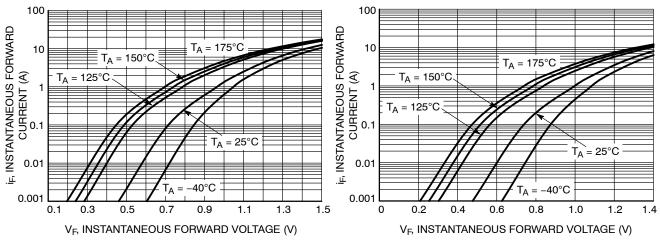


Figure 1. Typical Instantaneous Forward Characteristics

Figure 2. Maximum Instantaneous Forward Characteristics

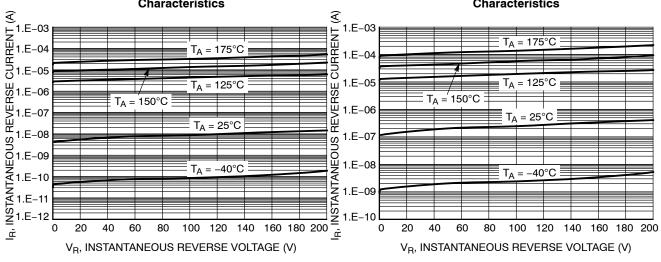


Figure 3. Typical Reverse Characteristics

Figure 4. Maximum Reverse Characteristics

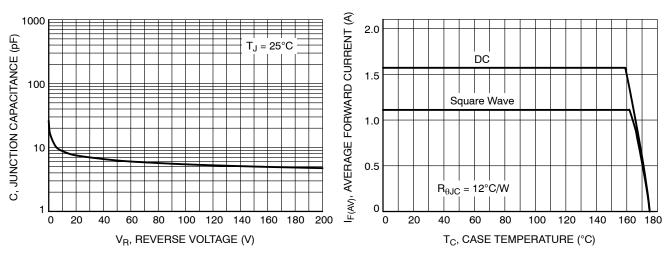


Figure 5. Typical Junction Capacitance

Figure 6. Current Derating

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TYPICAL CHARACTERISTICS (continued)

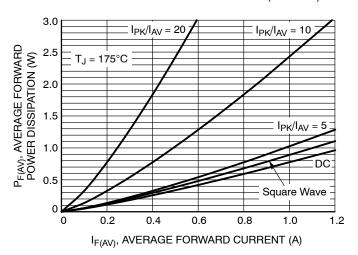


Figure 7. Forward Power Dissipation

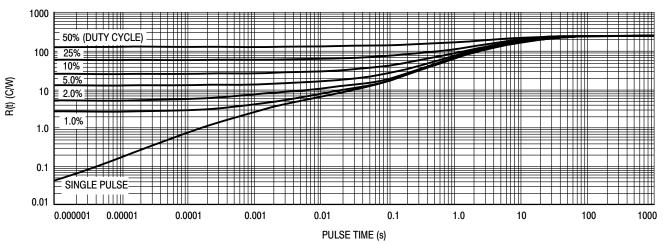


Figure 8. Thermal Response, Junction-to-Ambient (20 mm² pad)

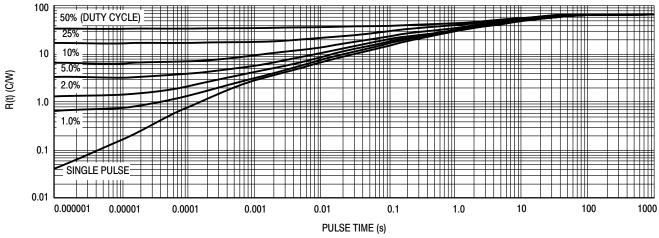


Figure 9. Thermal Response, Junction-to-Ambient (1 in² pad)

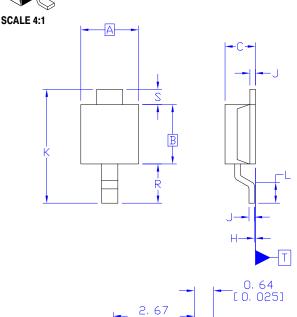
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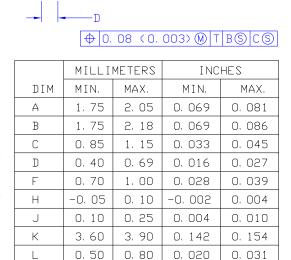
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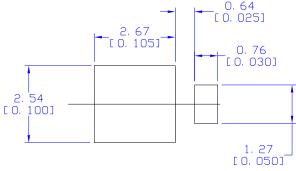




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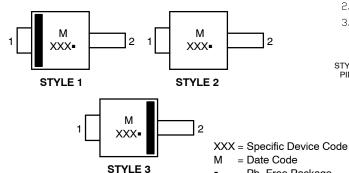




RECOMMENDED MOUNTING FOOTPRINT

ENERIC

GENERIC MARKING DIAGRAMS*



NOTES:

R

 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

1.50

1.20

0.50 REF

- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30mm FROM THE TERMINAL TIP.

STYLE 1: PIN 1. CATHODE 2. ANODE STYLE 2: PIN 1. ANODE OR CATHODE 2. CATHODE OR ANODE STYLE 3: PIN 1. ANODE 2. CATHODE

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may

(BI-DIRECTIONAL)

0.047

0.019 REF

0.059

STYLE 3 = Pb-Free Package not follow the Generic Marking.

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